

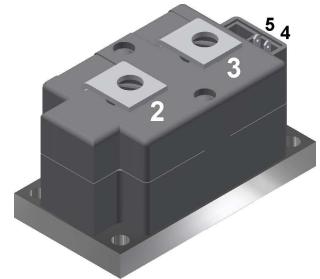
High Voltage Thyristor Module

V_{RRM} = 2000 V
 I_{TAV} = 600 A
 V_T = 1.06 V

Single Thyristor

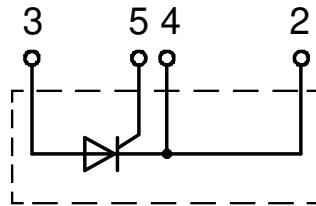
Part number

MCO600-20io1



Backside: isolated

 E72873



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: Y1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Disclaimer Notice

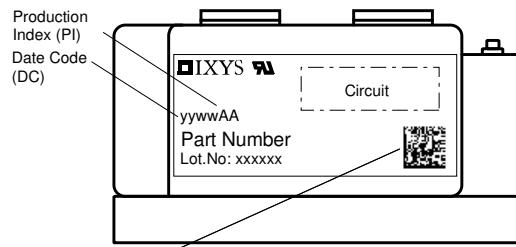
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Thyristor

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			2100	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			2000	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 2000 \text{ V}$ $V_{R/D} = 2000 \text{ V}$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		2 40	mA
V_T	forward voltage drop	$I_T = 600 \text{ A}$	$T_{VJ} = 25^\circ C$		1.12	V
		$I_T = 1200 \text{ A}$			1.34	V
		$I_T = 600 \text{ A}$ $I_T = 1200 \text{ A}$	$T_{VJ} = 125^\circ C$		1.06 1.33	V
I_{TAV}	average forward current	$T_C = 85^\circ C$	$T_{VJ} = 140^\circ C$		600	A
$I_{T(RMS)}$	RMS forward current	180° sine			940	A
V_{TO}	threshold voltage	$\left. \begin{array}{l} \text{slope resistance} \\ \end{array} \right\} \text{for power loss calculation only}$	$T_{VJ} = 140^\circ C$		0.81	V
r_T	slope resistance				0.4	mΩ
R_{thJC}	thermal resistance junction to case				0.065	K/W
R_{thCH}	thermal resistance case to heatsink			0.02		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ C$		1770	W
I_{TSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		15.0	kA
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		16.2	kA
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 140^\circ C$		12.8	kA
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		13.8	kA
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$		1.13	MA²s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		1.09	MA²s
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 140^\circ C$		812.8	kA²s
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		788.8	kA²s
C_J	junction capacitance	$V_R = 700 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$	469		pF
P_{GM}	max. gate power dissipation	$t_p = 30 \mu s$	$T_C = 140^\circ C$		120	W
		$t_p = 300 \mu s$			60	W
					20	W
P_{GAV}	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 140^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 1800 \text{ A}$			100	A/μs
		$t_p = 200 \mu s; di_G/dt = 1 \text{ A}/\mu s;$				
		$I_G = 1 \text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 600 \text{ A}$			500	A/μs
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^\circ C$		1000	V/μs
		$R_{GK} = \infty$; method 1 (linear voltage rise)				
V_{GT}	gate trigger voltage	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ C$		2	V
			$T_{VJ} = -40^\circ C$		3	V
I_{GT}	gate trigger current	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ C$		300	mA
			$T_{VJ} = -40^\circ C$		400	mA
V_{GD}	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^\circ C$		0.25	V
I_{GD}	gate non-trigger current				10	mA
I_L	latching current	$t_p = 30 \mu s$	$T_{VJ} = 25^\circ C$		400	mA
		$I_G = 1 \text{ A}; di_G/dt = 1 \text{ A}/\mu s$				
I_H	holding current	$V_D = 6 \text{ V}$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		300	mA
t_{gd}	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25^\circ C$		2	μs
		$I_G = 1 \text{ A}; di_G/dt = 1 \text{ A}/\mu s$				
t_q	turn-off time	$V_R = 100 \text{ V}; I_T = 600 \text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ C$	$di/dt = 10 \text{ A}/\mu s$ $dv/dt = 50 \text{ V}/\mu s$ $t_p = 200 \mu s$	350		μs

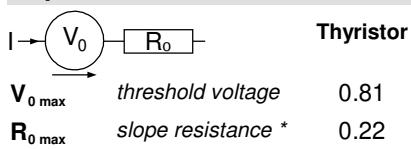
Package Y1

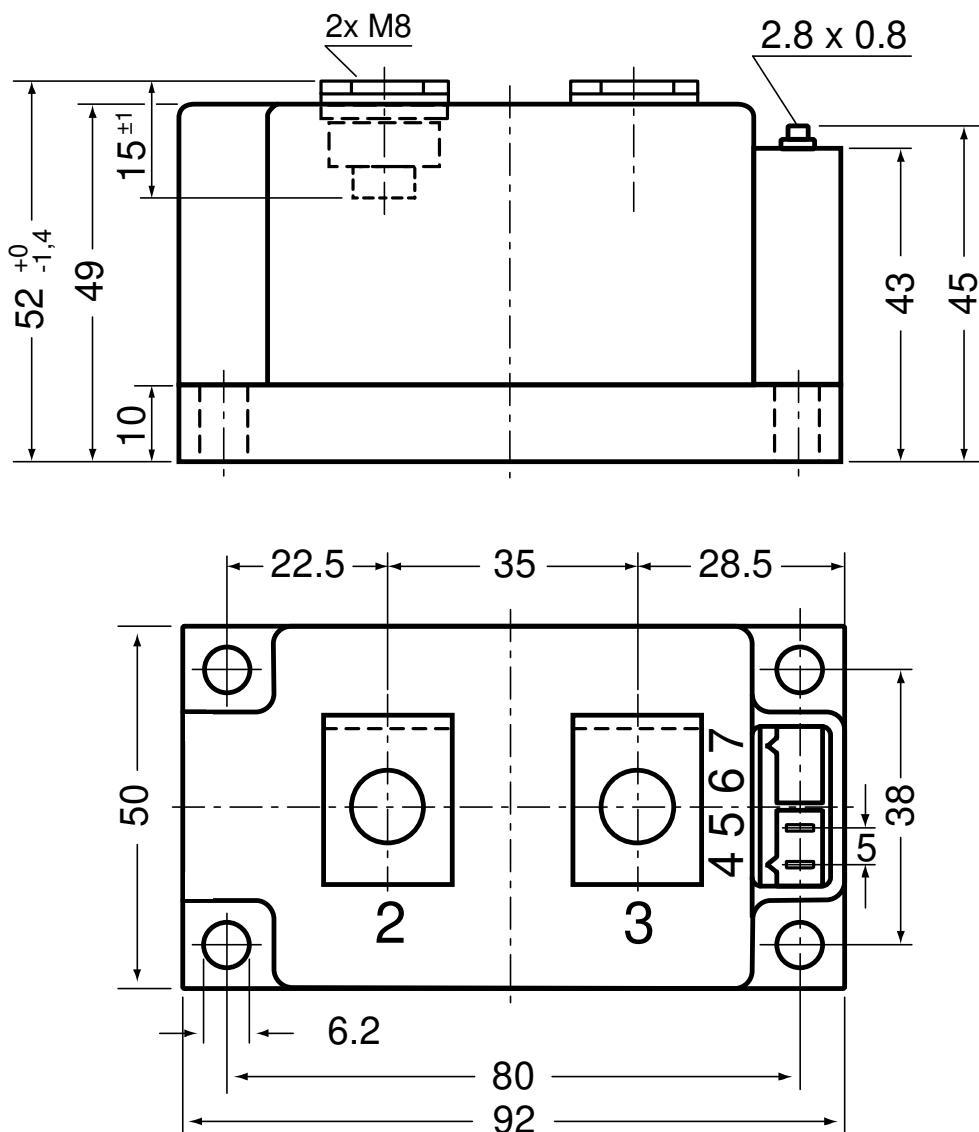
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
I_{RMS}	RMS current	per terminal			600	A
T_{VJ}	virtual junction temperature		-40		140	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight				650		g
M_D	mounting torque		4.5		7	Nm
M_T	terminal torque		11		13	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	16.0			mm
$d_{Spb/Apb}$		terminal to backside	25.0			mm
V_{ISOL}	isolation voltage	$t = 1$ second $t = 1$ minute	3600 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000		V V



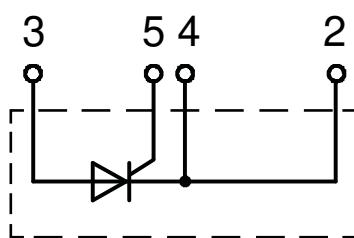
Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31),
blank (32), serial no.# (33-36)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCO600-20io1	MCO600-20io1	Box	2	474320

Equivalent Circuits for Simulation
* on die level
 $T_{VJ} = 140^\circ\text{C}$


Outlines Y1

Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red
Type ZY 180L (L = Left for pin pair 4/5) UL 758, style 3751



Thyristor

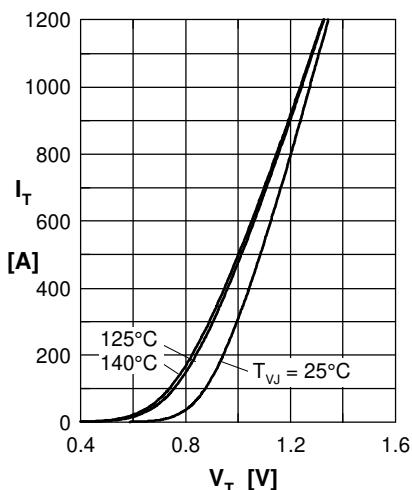


Fig. 1 Forward characteristics

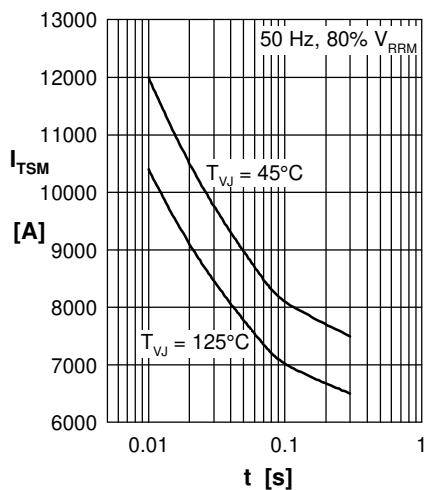


Fig. 2 Surge overload current

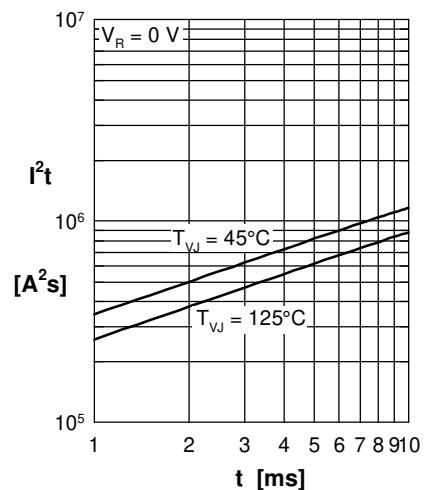


Fig. 3 I^2t versus time (1-10 ms)

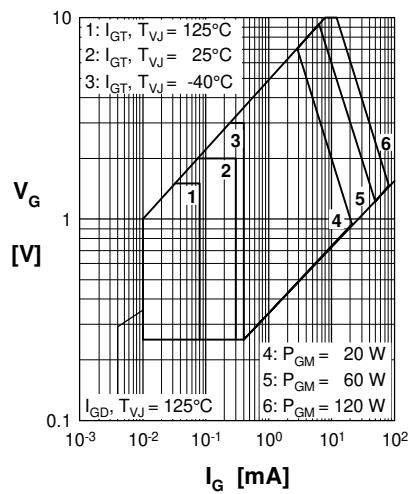


Fig. 4 Gate trigger characteristics

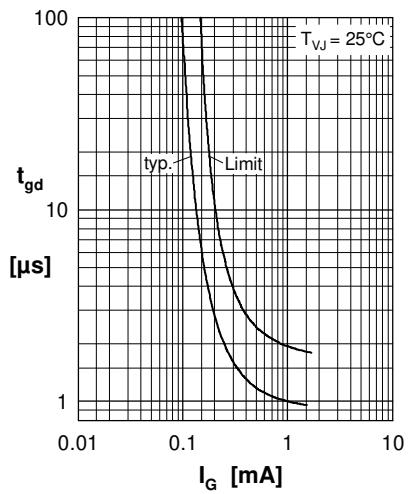


Fig. 5 Gate controlled delay time

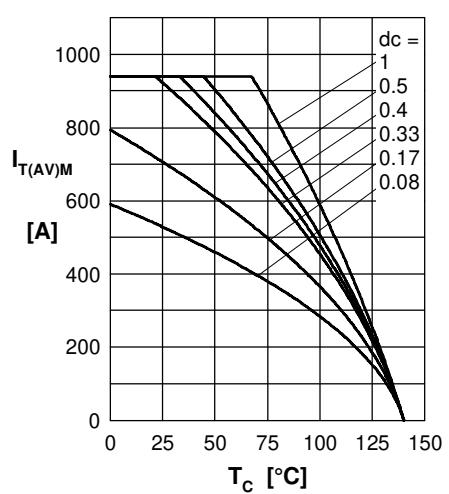


Fig. 6 Max. forward current at case temperature

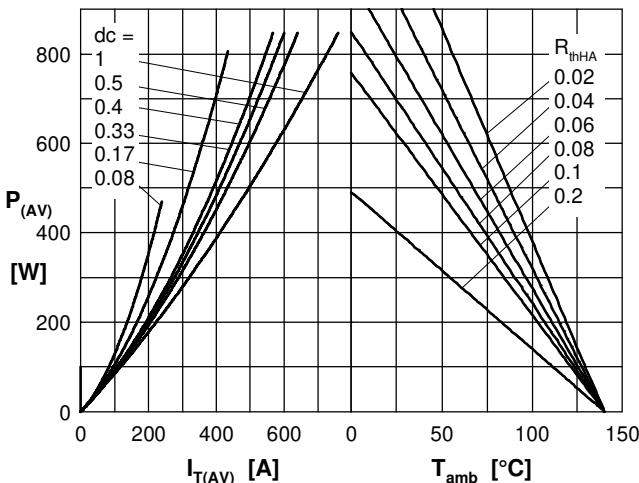


Fig. 7a Power dissipation versus direct output current
Fig. 7b and ambient temperature

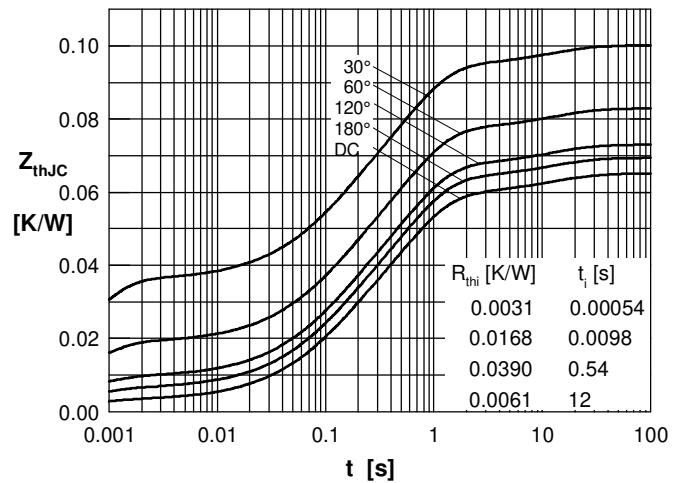


Fig. 7b Transient thermal impedance